

LED ARRAY



LA38B-73/DUV-PF-A02

DATA SHEET

DOC. NO:	QW0905-LA38B-73/DUV-PF-A02

REV. : B	
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DATE : 10 - Jun. - 2011







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Absolute Maximum Ratings at Ta=25 $^\circ\!\mathrm{C}$

Parameter	Symbol	Ratings	UNIT	
Farameter	Gymbol	DUV		
Forward Current	lF	30	mA	
Peak Forward Current Duty 1/10@10KHz	IFP	100	mA	
Power Dissipation	PD	120	mW	
Reverse Current @5V	lr	50	μ A	
Electrostatic Discharge(*)	ESD	150	V	
Operating Temperature	Topr	-20 ~ +80	°C	
Storage Temperature	Tstg	-30 ~ +100	°C	

* Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing these LED. All devices, equipment and machinery must be properly grounded.

Typical Electrical & Optical Characteristics (Ta=25 °C)

PART NO	MATERIAL	COLOR		Peak wave length λ P nm		Spectral halfwidth $\triangle \lambda$ nm	Forward voltage @20mA(V)		Luminous intensity @20mA(mcd)		Viewing angle $2 \theta 1/2$ (deg)
		Emitted	Lens	Min.	Max.		Min.	Max.	Min.	Тур.	
LA38B-73/DUV-PF-A02	InGaN	Purple	Water Clear	385	390	20	3.0	4.0	350	700	20

Note : 1. The forward voltage data did not including $\pm 0.1V$ testing tolerance.

2. The luminous intensity data did not including $\pm 15\%$ testing tolerance.



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Typical Electro-Optical Characteristics Curve

DUV CHIP



Fig.3 Forward Current vs. Wavelength



Fig.4 Relative Intensity vs. Wavelength





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Soldering Condition(Pb-Free)

1.Iron:

Soldering Iron:30W Max Temperature 350 °C Max Soldering Time:3 Seconds Max(One Time) Distance:2mm Min(From solder joint to case)

2. Wave Soldering Profile

Dip Soldering Preheat: 120°C Max Preheat time: 60seconds Max Ramp-up 2°C/sec(max) Ramp-Down:-5°C/sec(max) Solder Bath:260°C Max Dipping Time:3 seconds Max Distance:2mm Min(From solder joint to case)





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Reliability Test:

Test Item	Test Condition	Description	Reference Standard		
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resisance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1		
High Temperature Storage Test	1.Ta=105 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10		
Low Temperature Storage Test	1.Ta=-40 °C±5 °C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12		
High Temperature High Humidity Test	1.Ta=65 ℃ ±5 ℃ 2.RH=90 %~95 % 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hous.	MIL-STD-202:103B JIS C 7021: B-11		
Thermal Shock Test	1.Ta=105 ℃±5℃&-40℃±5℃ (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011		
Solder Resistance Test	1.T.Sol=260 ℃±5 ℃ 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1		
Solderability Test	1.T.Sol=230 ℃±5℃ 2.Dwell time=5±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2		